

# **Dual Channel Small Outline Optoisolators Darlington Output**

The MOCD223 device consists of two gallium arsenide infrared emitting diodes optically coupled to two monolithic silicon phototransistor darlington detectors, in a surface mountable, small outline, plastic package. It is ideally suited for high density applications that require low input current and eliminates the need for through-the-board mounting.

- Dual Channel Coupler
- Convenient Plastic SOIC-8 Surface Mountable Package Style •
- High Output Current (I<sub>C</sub>) (500% min) @ 1 mA Input Current •
- Minimum V(BR)CEO of 30 Volts Guaranteed
- Standard SOIC-8 Footprint, with 0.050" Lead Spacing .
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering .
- High Input–Output Isolation of 3000 Vac (rms) Guaranteed
- Meets U.L. Regulatory Requirements, File #E90700, Volume 2 .

#### **Ordering Information:**

- To obtain MOCD223 in tape and reel, add R2 suffix to device number as follows: R2 = 2500 units on 13" reel
- To obtain MOCD223 in guantities of 50 (shipped in sleeves) no suffix

#### **Marking Information:**

MOCD223 = D223



# MOCD223

DUAL CHANNEL SMALL OUTLINE **OPTOISOLATOR** DARLINGTON OUTPUT







- 4. LED 2 CATHODE
- 5. EMITTER 2
- 6. COLLECTOR 2
- 7. EMITTER 1
- 8. COLLECTOR 1



### **MAXIMUM RATINGS** — continued ( $T_A = 25^{\circ}C$ unless otherwise noted)

R	ating		5	Symbol	Value		Unit
OTAL DEVICE							
Input–Output Isolation Voltage <sup>(1,2)</sup> (60 Hz, 1.0 sec. duration)				VISO	3000		Vac(rms)
Total Device Power Dissipation @ Tp Derate above 25°C	λ = 25°C			PD	250 2.94		mW mW/°C
Ambient Operating Temperature Ran	ge <sup>(3)</sup>			TA	-45 to +1	00	°C
Storage Temperature Range <sup>(3)</sup>				T <sub>stg</sub>	-45 to +1	25	°C
Lead Soldering Temperature (1/16" from case, 10 sec. duration)				—	260		°C
ELECTRICAL CHARACTERISTIC	<b>CS</b> ( $T_A = 25^{\circ}C$ unless otherwise	e noted)( <sup>4)</sup>					
Characteris	stic	Symbol		Min	<b>Тур(</b> <sup>4)</sup>	Max	Unit
INPUT LED							
Forward Voltage (I <sub>F</sub> = 1.0 mA)		٧ <sub>F</sub>		—	1.05	1.3	V
Reverse Leakage Current ( $V_R = 6.0$	V)	۱ <sub>R</sub>		—	0.1	100	μΑ
Capacitance		С		—	18	_	pF
OUTPUT DARLINGTON							
Collector–Emitter Dark Current	$(V_{CE} = 5.0 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C})$	ICEO1		_	1.0	50	nA
	$(V_{CE} = 5.0 \text{ V}, \text{ T}_{A} = 100^{\circ}\text{C})$	I <sub>CEO</sub> 2		_	1.0	_	μΑ
Collector-Emitter Breakdown Voltage	e (I <sub>C</sub> = 100 μA)	V(BR)CEC	С	30	90		V
Emitter–Collector Breakdown Voltage (I <sub>E</sub> = 100 μA)		V(BR)ECO	С	7.0	7.8		V
Collector–Emitter Capacitance (f = 1.0 MHz, V <sub>CE</sub> = 0)		CCE		—	5.5		pF
COUPLED							
Output Collector Current (I <sub>F</sub> = 1.0 mA, $V_{CE}$ = 5.0 V)	MOCD223	I <sub>C</sub> (CTR) <sup>(5</sup>	5)	5.0 (500)	10 (1000)		mA (%)
Collector-Emitter Saturation Voltage	$(I_{C} = 500 \ \mu\text{A}, I_{F} = 1.0 \ \text{mA})$	VCE(sat)	)	—	-	1.0	V
Turn–On Time (I <sub>F</sub> = 5.0 mA, V <sub>CC</sub> = 1	10 V, R <sub>L</sub> = 100 Ω)	ton		—	3.5	_	μs
Turn–Off Time (I <sub>F</sub> = 5.0 mA, V <sub>CC</sub> = 1	10 V, R <sub>L</sub> = 100 Ω)	toff		—	95	_	μs
Rise Time (I <sub>F</sub> = 5.0 mA, $V_{CC}$ = 10 V,	R <sub>L</sub> = 100 Ω)	tr		—	1.0	_	μs
Fall Time (I <sub>F</sub> = 5.0 mA, V <sub>CC</sub> = 10 V,	R <sub>L</sub> = 100 Ω)	t <sub>f</sub>		—	2.0	_	μs
Input–Output Isolation Voltage (f = 60	) Hz, t = 1.0 sec.) <sup>(1,2)</sup>	VISO		3000	_	_	Vac(rms)
Isolation Resistance $(V_{I-O} = 500 V)$	2)	RISO		10 <sup>11</sup>	_		Ω
Isolation Capacitance ( $V_{I-O} = 0, f = 1$	1.0 MHz) <sup>(2)</sup>	C <sub>ISO</sub>			0.2	_	pF

1. Input–Output Isolation Voltage,  $V_{\mbox{\scriptsize ISO}},$  is an internal device dielectric breakdown rating.

2. For this test, pins 1, 2, 3 and 4 are common, and pins 5, 6, 7 and 8 are common.

3. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

4. Always design to the specified minimum/maximum electrical limits (where applicable).

5. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .



# MOCD223





Figure 1. LED Forward Voltage versus Forward Current



Figure 2. Output Current versus Input Current



TA, AMBIENT TEMPERATURE (°C)

Figure 5. Dark Current versus Ambient Temperature

Figure 6. Capacitance versus Voltage



# MOCD223

# PACKAGE DIMENSIONS





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Products groups         Analog and Mixed         Signal         Discrete         Interface         Logic         Microcontrollers         Non-Volatile         Memory         Optoelectronics         Markets and         applications         New products         Product selection and         parametric search         Cross-reference         search	MOCD223-M SO8 Dual Channel Photodarlington Coupler Contents General description   Ordering information   Product status/pricing/packaging   Safety agency certificates General description The MOCD223 device consists of two gallium arsenide infrared emitting diodes optically coupled to two monolithic silicon phototransistor detectors, in a surface mountable, small outline, plastic package. They are ideally suited for high density applications and eliminate the need for through- the-board mounting.	Datasheet <u>Download this</u> <u>datasheet</u> PDF e-mail this datash [E- This page Print version	Related Links  Request samples  Dotted line How to order products  Dotted line Product Change Notices (PCNs)  Dotted line Distributor and field sales representatives Dotted line Quality and reliability Dotted line Design tools
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technical support	mountable package style		
my Fairchild	• High output current (I <sub>C</sub> ) (500% min) @		
company	• Minimum $V_{(BR)CEO}$ of 30 volts		
	<ul> <li>guaranteed</li> <li>Standard SOIC - 8 footprint with a 0.050-inch lead spacing</li> <li>Compatible with dual wave, vapor phase and IR reflow soldering</li> <li>High input - Output isolation of 3000 VAC (RMS) guaranteed</li> <li>Underwriters Laboratory (UL) recognized - File #E90700, Volume 2</li> </ul>		

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### Ordering information

The following options can be ordered with this part:

Option	Order Entry Identifier	Description
R1	R1	Surface-Mount Lead Bend Tape and Reel (500-pc reel)
R2	R2	Surface-Mount Lead Bend Tape and Reel (2500-pc reel)

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
MOCD223-M	Full Production	\$0.405	SOIC	8	RAIL
MOCD223R1-M	Full Production	\$0.413	SOIC	8	TAPE REEL
MOCD223R2-M	Full Production	\$0.413	SOIC	8	TAPE REEL

\* 1,000 piece Budgetary Pricing

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Safety agency certificates

Cetificate	Agency	
<u>136616</u> (161 K)	VDE	VDE Pruf-und Zertifizierungsinstitut
E90700, Vol. 2 (254 K)	UL	Underwriters Laboratories Inc.

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<u>Cross-reference</u> <u>search</u>	4N29A-M replaced by <u>4N29</u>	4N30-M replaced by <u>4N30</u>	by <u>4129</u> 4N31-M replaced           by <u>4N31</u>	
technical information	4N32-M replaced by <u>4N32</u>	4N33-M replaced by <u>4N33</u>	<u>4N35-M</u>	
technical support	- <u>4N36-M</u>	<u>4N37-M</u>	4N38- <b>M</b> replaced by <u>4N38</u>	
my Fairchild	4N38A-M replaced by 4N38			
company				

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Datasheets for products beginning with CNY

<u>CNY17-1-M</u>	<u>CNY17-2-M</u>	<u>CNY17-3-M</u>

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Datasheets for products beginning with H11

<u>H11A1-M</u>	H11AA1-M replaced by H11AA1	H11AA2-M replaced by H11AA2
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H11AA3-M replaced by H11AA3	H11AA4-M replaced by H11AA4	H11AV1-M
H11AV1A-M	<u>H11AV2-M</u>	H11AV2A-M
H11B1-M replaced by H11B1	H11B3-M replaced by H11B3	H11D1-M replaced by H11D1
H11D2-M replaced by H11D2	H11G1-M replaced by H11G1	H11G2-M replaced by H11G2
H11G3-M replaced by H11G3	<u>H11L1-M</u>	H11L2-M
H11L3-M		

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Datasheets for products beginning with MCT

	MCT2-M	MCT2E-M	
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Datasheets for products beginning with MOC

<u>MOC205-M</u>	MOC206-M	<u>MOC207-M</u>
<u>MOC208-M</u>	<u>MOC211-M</u>	<u>MOC212-M</u>
<u>MOC213-M</u>	<u>MOC215-M</u>	MOC216-M
<u>MOC217-M</u>	<u>MOC223-M</u>	MOC256-M
MOC3010-M	<u>MOC3011-M</u>	MOC3012-M
MOC3020-M	<u>MOC3021-M</u>	<u>MOC3022-M</u>
MOC3023-M	<u>MOC3031-M</u>	<u>MOC3032-M</u>
<u>MOC3033-M</u>	<u>MOC3041-M</u>	<u>MOC3042-M</u>
<u>MOC3043-M</u>	<u>MOC3051-M</u>	<u>MOC3052-M</u>
<u>MOC3061-M</u>	<u>MOC3062-M</u>	<u>MOC3063-M</u>
<u>MOC3081-M</u>	<u>MOC3081-M</u>	<u>MOC3083-M</u>
MOC3162-M	MOC3163-M	<u>MOC5007-M</u>
<u>MOC5008-M</u>	<u>MOC5009-M</u>	MOC8030-M replaced by MOC8030

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MOC8050-M replaced by MOC8050	MOC8080-M replaced by MOC8080	MOC8100-M
MOC8204-M replaced by MOC8204	MOCD207-M	MOCD208-M
MOCD211-M	MOCD213-M	MOCD217-M
MOCD223-M		

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